

## Maximum Ratings (@T<sub>A</sub> = +25°C unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	20	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	14	V
Average Rectified Output Current (See Figure 1)	I <sub>O</sub>	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	6	A

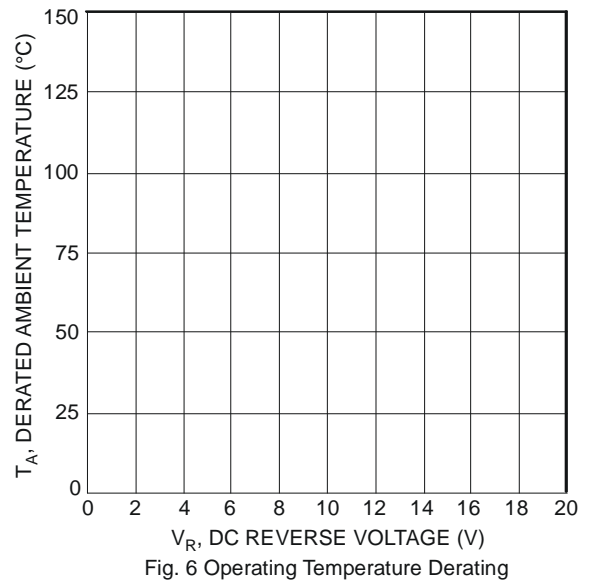
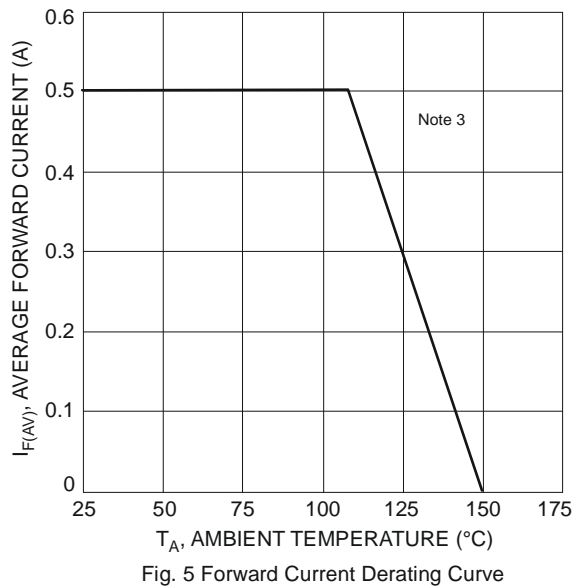
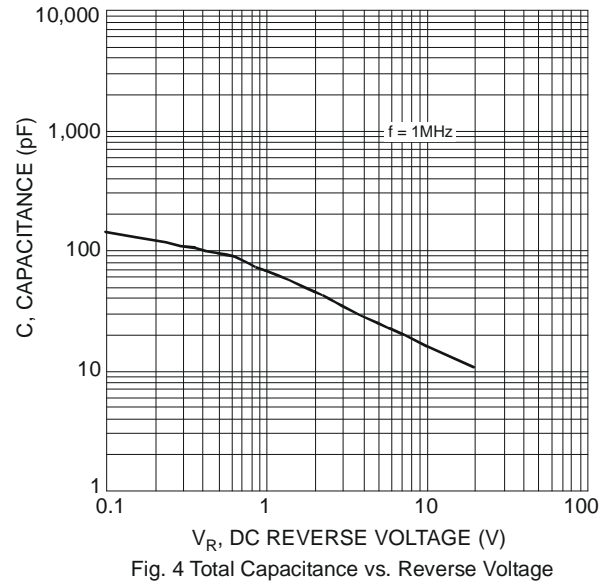
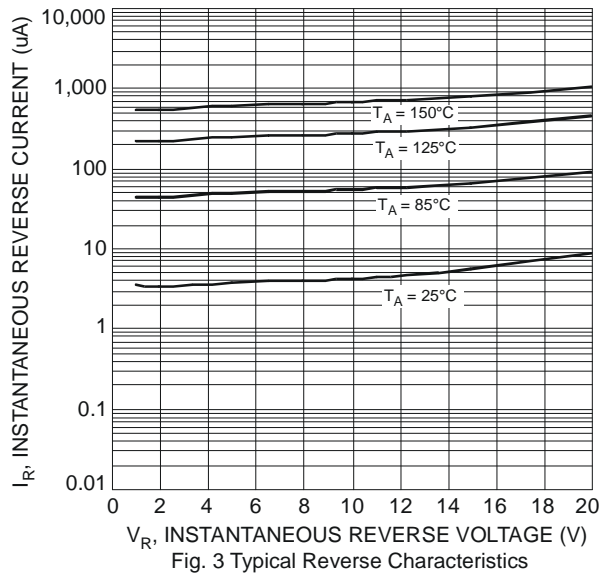
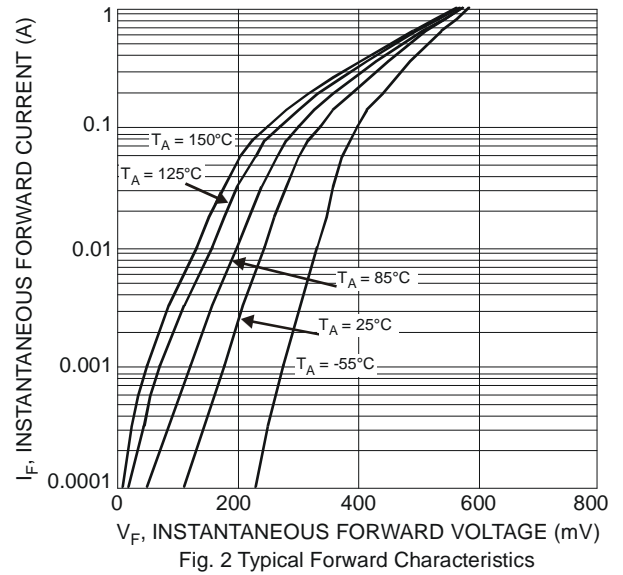
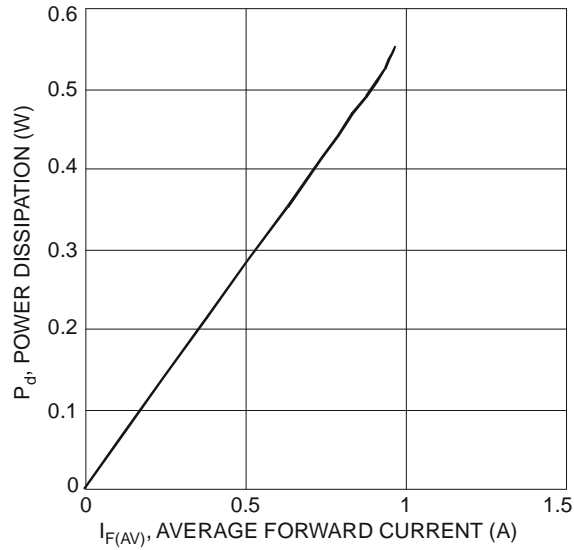
## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance (Note 5)	R <sub>θJA</sub>	224	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	20	—	—	V	I <sub>R</sub> = 50μA
Forward Voltage Drop	V <sub>F</sub>	—	0.34 0.25 0.38 0.31 0.47 0.42	0.38 0.28 0.42 0.34 0.50 0.45	V	I <sub>F</sub> = 0.1A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.1A, T <sub>J</sub> = +150°C I <sub>F</sub> = 0.2A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.2A, T <sub>J</sub> = +150°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = +25°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = +150°C
Leakage Current (Note 6)	I <sub>R</sub>	—	6 1.5	50 5	μA mA	V <sub>R</sub> = 20V, T <sub>J</sub> = +25°C V <sub>R</sub> = 20V, T <sub>J</sub> = +150°C

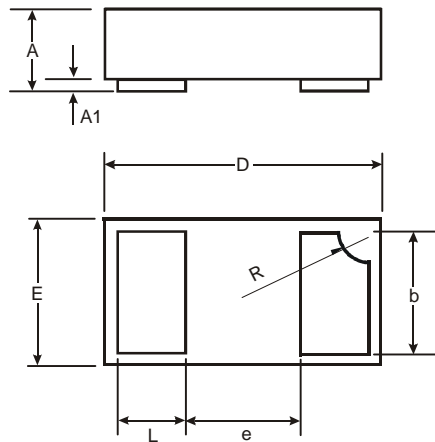
Notes: 5. Device mounted on FR-4 substrate. 2" x 2" 2oz. Copper, single sided PCB board.  
6. Short duration pulse test used to minimize self-heating effect.



## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

**X2-DFN1006-2**

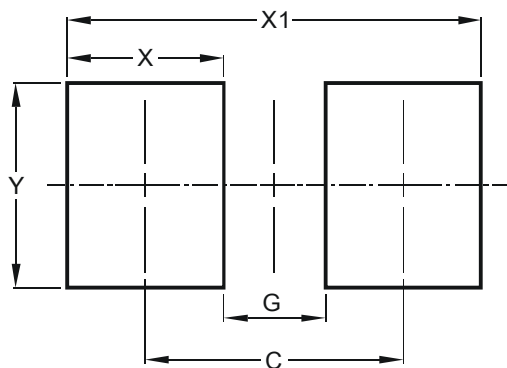


X2-DFN1006-2			
Dim	Min	Max	Typ
A	0.34	0.4	0.37
A1	0	0.05	0.03
b	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	—	—	0.40
L	0.20	0.30	0.25
R	0.05	0.15	0.10
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

**X2-DFN1006-2**



Dimensions	Value (in mm)
C	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70

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